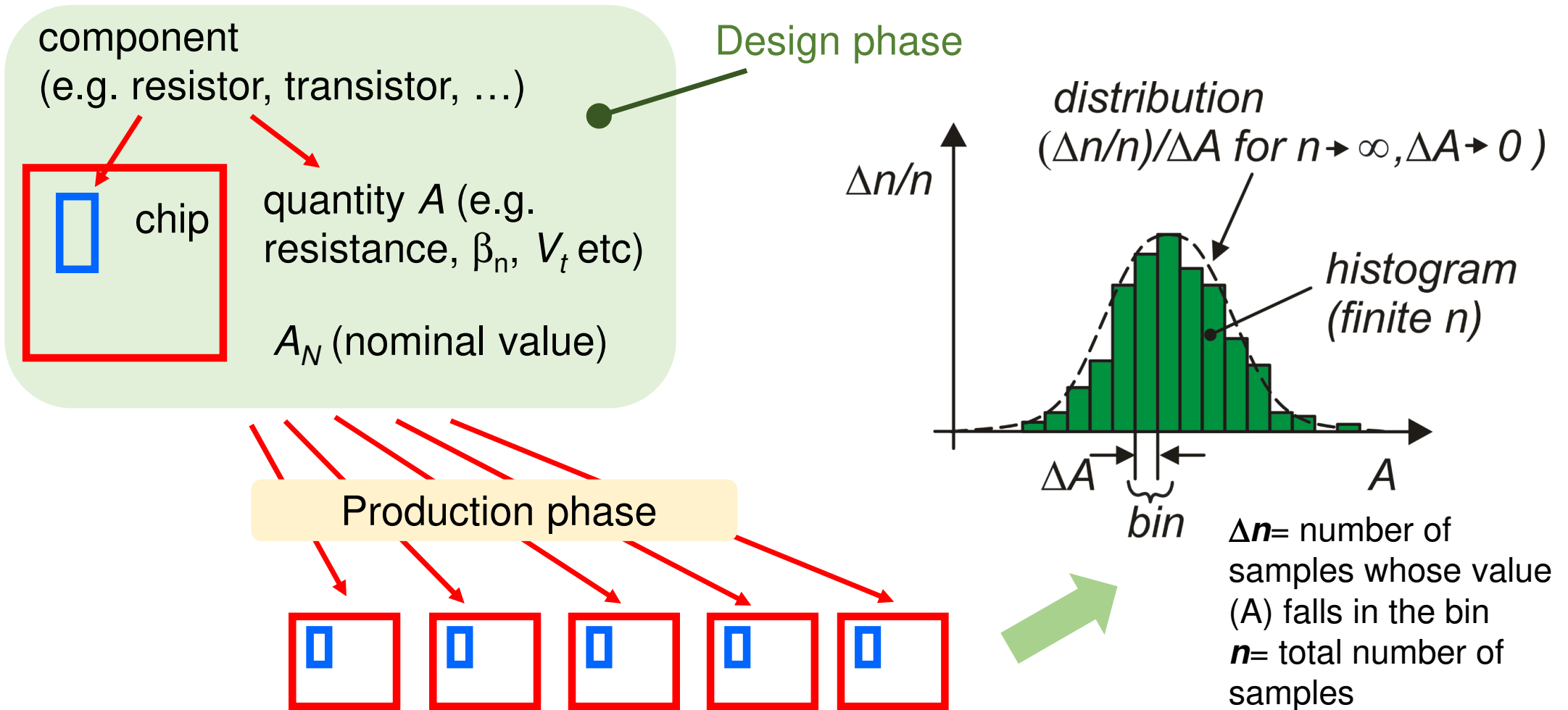
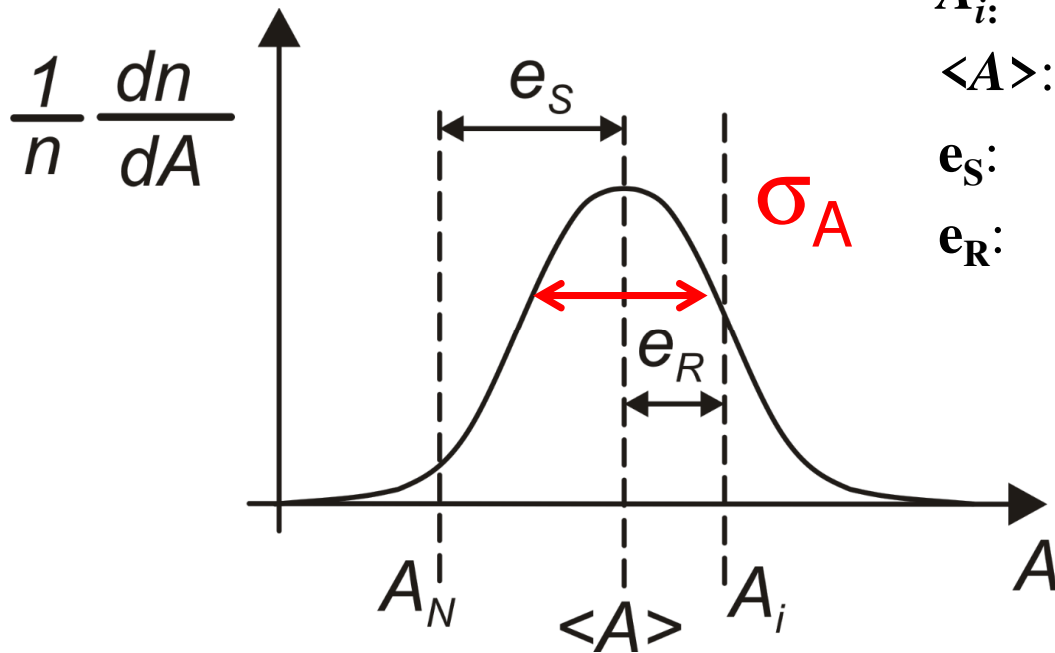


# Process Errors in Integrated Circuits



## Components of the error and statistical representation



$A_N$ : nominal value

$A_i$ :  $A$  for a generic  $i$ -th component.

$\langle A \rangle$ : the mean of the distribution.

$e_S$ : Systematic error =  $\langle A \rangle - A_N$

$e_R$ : Random error for the  $i$ -th component  
 $e_R = A_i - \langle A \rangle$ .

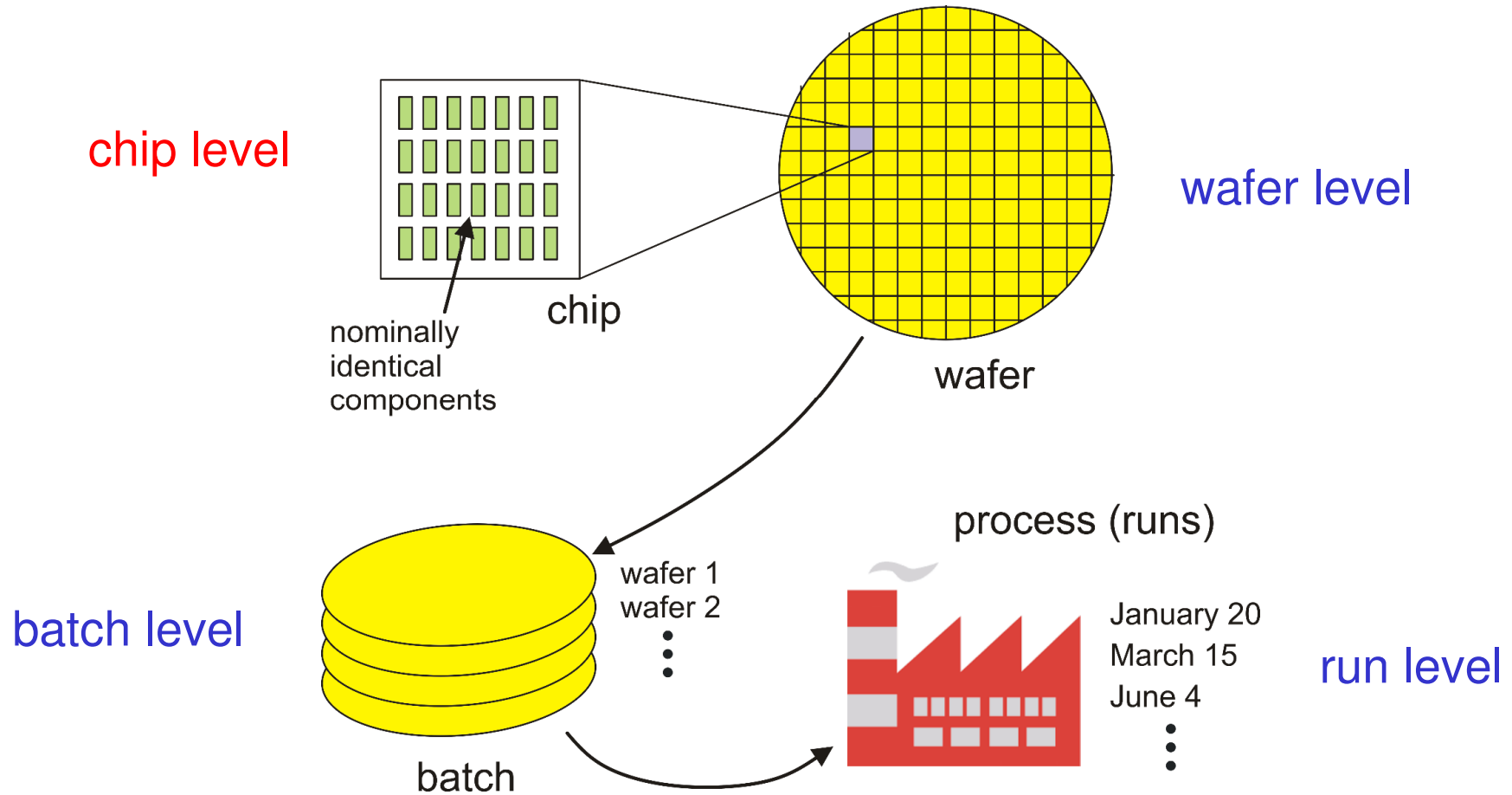
Random error: standard deviation

$$\sigma_A = \sqrt{\left\langle (A - \langle A \rangle)^2 \right\rangle}$$

# Confidence intervals

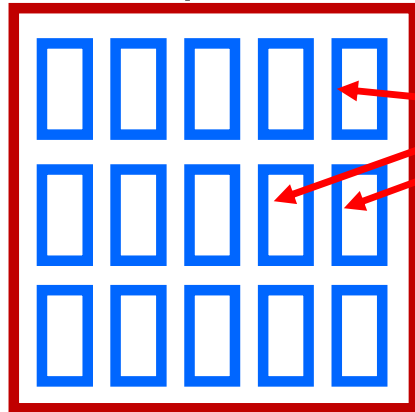
Max deviation from the mean	$\pm \sigma$	$\pm 2\sigma$	$\pm 3\sigma$	$\pm 4\sigma$
Fraction of data within the interval	68.3 %	95.4 %	99.7 %	99.994 %
Fraction of data outside the interval	31.7 %	4.6 %	0.3 %	0.006 %

# Errors in Integrated Circuits: Levels



# Local and global errors: means

i-th chip



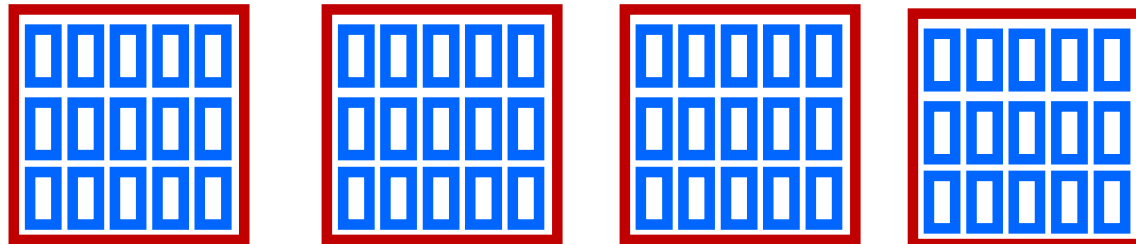
nominally identical components

$$\langle A \rangle_{chip}$$

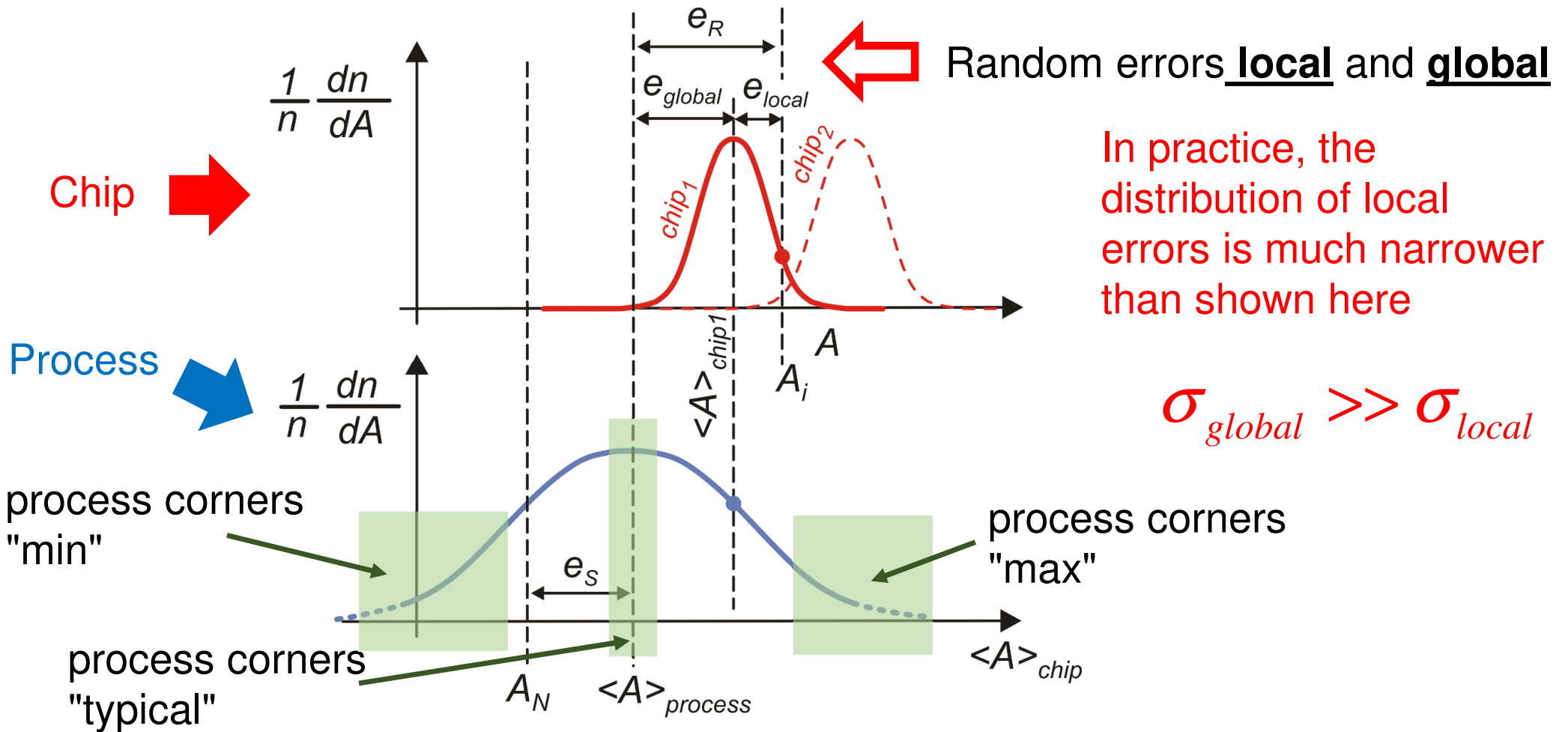
varies from chip to chip (local mean)

$$\langle A \rangle_{process}$$

property of the whole process (global mean)

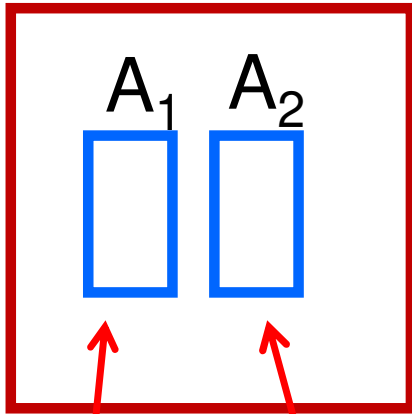


# Local and global errors



# Matching errors: definition

Matching error (or mismatch)



$$\begin{cases} \Delta A = A_1 - A_2 \\ \bar{A} = \frac{A_1 + A_2}{2} \end{cases} \iff \begin{cases} A_1 = \bar{A} + \frac{\Delta A}{2} \\ A_2 = \bar{A} - \frac{\Delta A}{2} \end{cases}$$

Component 1

Component 2



Nominally identical and placed on the same chip

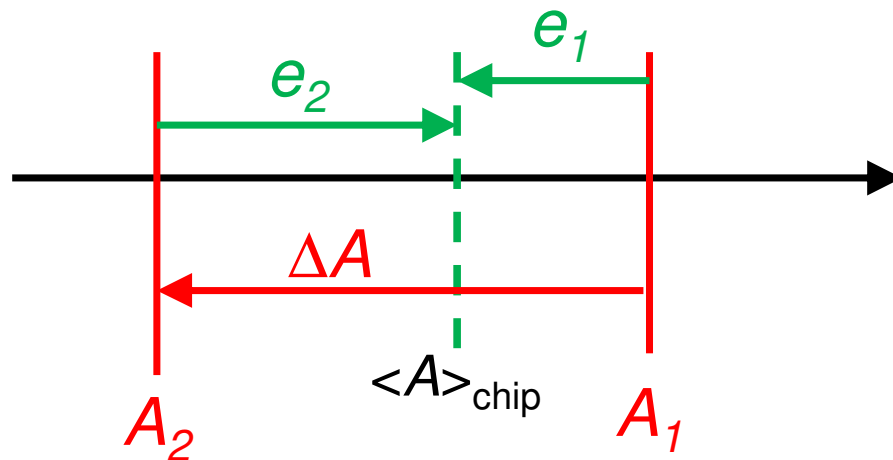
Random Matching errors: Main causes

- Microscopic irregularities (local granularity)
- Parameter gradients

## Relationship between matching error and local error

$$A_1 = \langle A \rangle_{chip} + e_1$$

$$A_2 = \langle A \rangle_{chip} + e_2 \quad \Delta A = A_1 - A_2 = e_1 - e_2$$





# Matching errors: Microscopic irregularities

$N$  = number of dopants atoms within the component area

$\Delta N = N_1 - N_2$  **matching error**

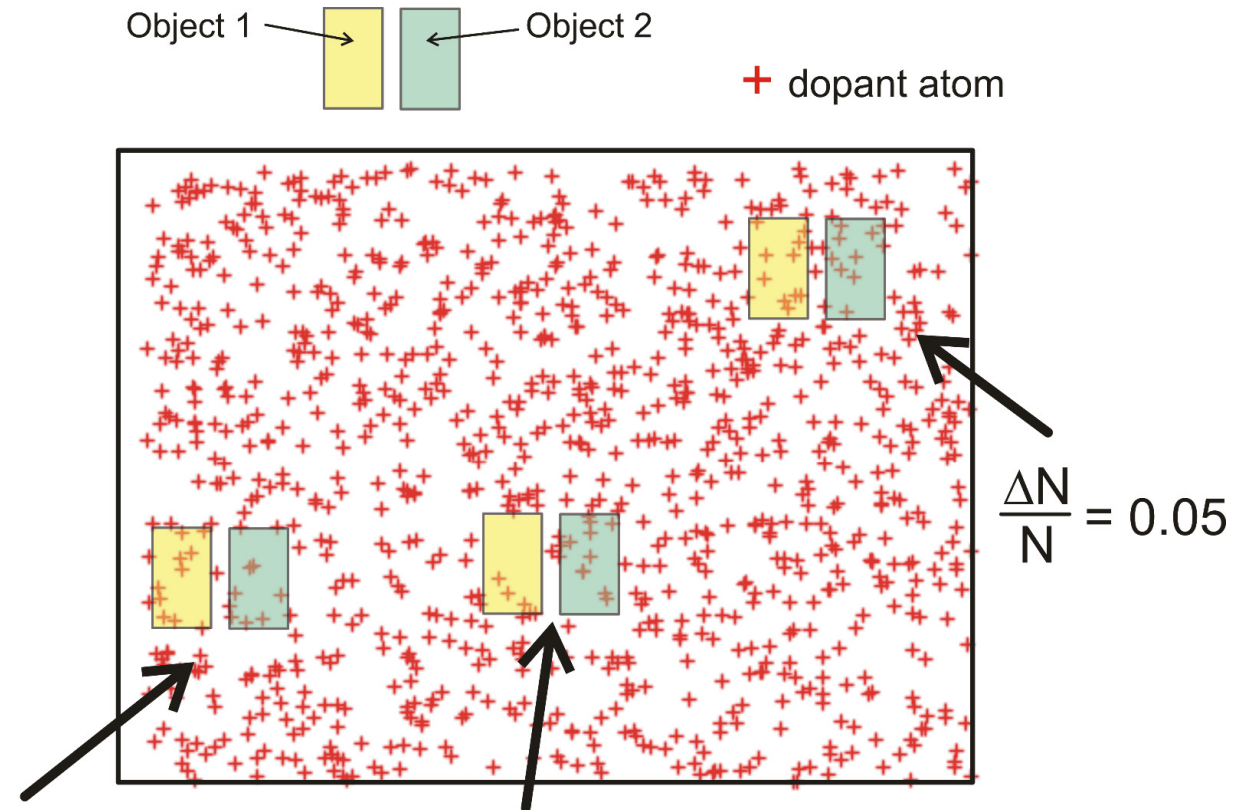
Depending on the position  $\Delta N$  is subjected to large variations.

**The important parameter is: Relative matching error:**

$$\frac{\Delta N}{N} \leftarrow \frac{N_1 + N_2}{2}$$

$$\frac{\Delta N}{N} = 0.12$$

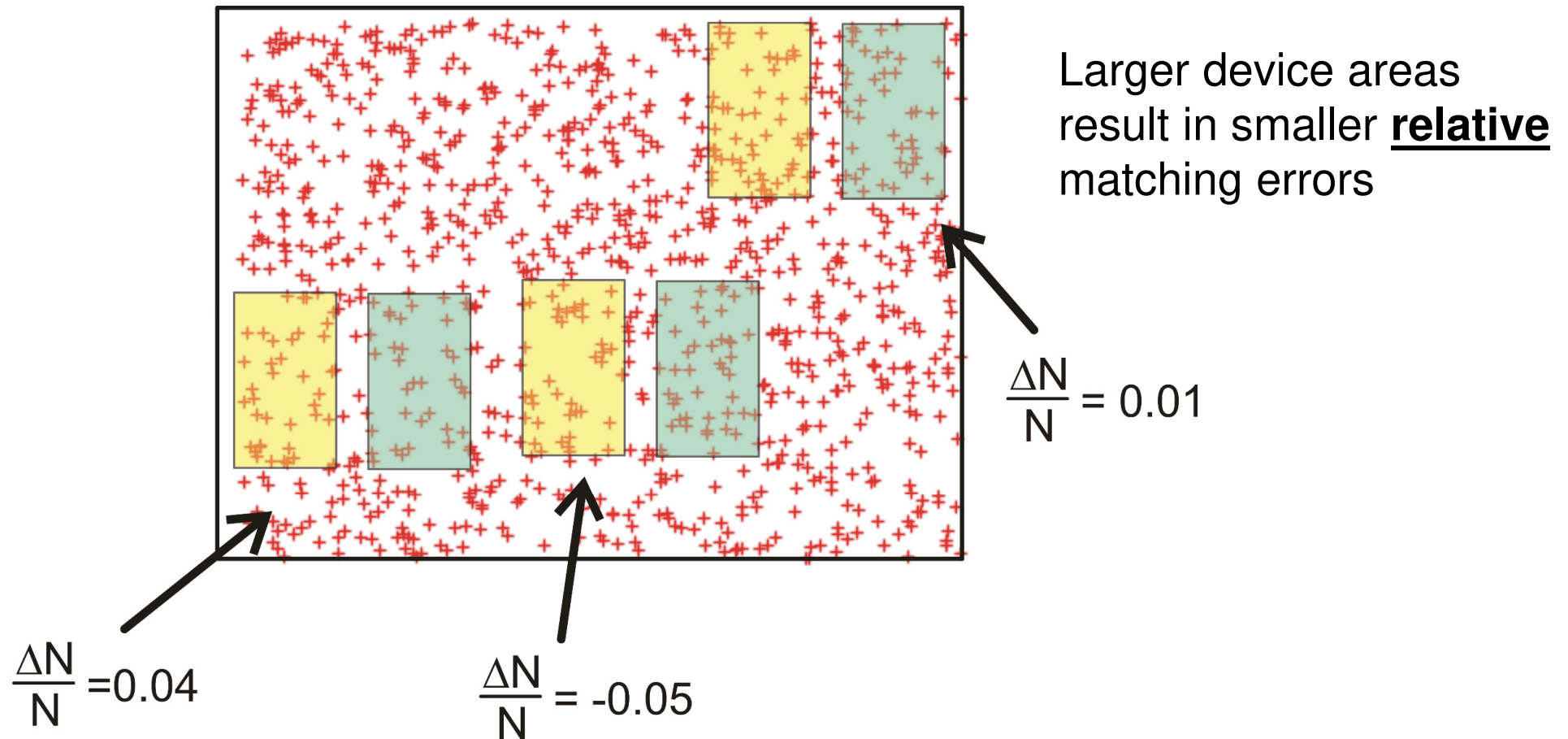
$$\frac{\Delta N}{N} = -0.38$$



## Matching errors: Microscopic irregularities

- The number of dopants atoms affects several properties such as effective sheet resistance and MOSFET threshold voltage
- The example can be replicated for other quantities, such as oxide thickness, where the crosses in the figure may represent local maxima or minima
- The large fluctuation of  $\Delta N/N$  can be ascribed to the small area of the devices shown in the example. For even smaller devices its is likely that one of the two devices does not include any dopant atom :  $\Delta N/N$  may exceed unity (100 % error).

# Microscopic irregularities: effect of device area



## Microscopic irregularities: the Pelgrom model

$$\left\{ \begin{array}{l} \sigma_{\Delta V_t} = \frac{C_{Vt}}{\sqrt{WL}} \\ \sigma_{\frac{\Delta\beta}{\beta}} = \frac{C_{\beta}}{\sqrt{WL}} \end{array} \right.$$

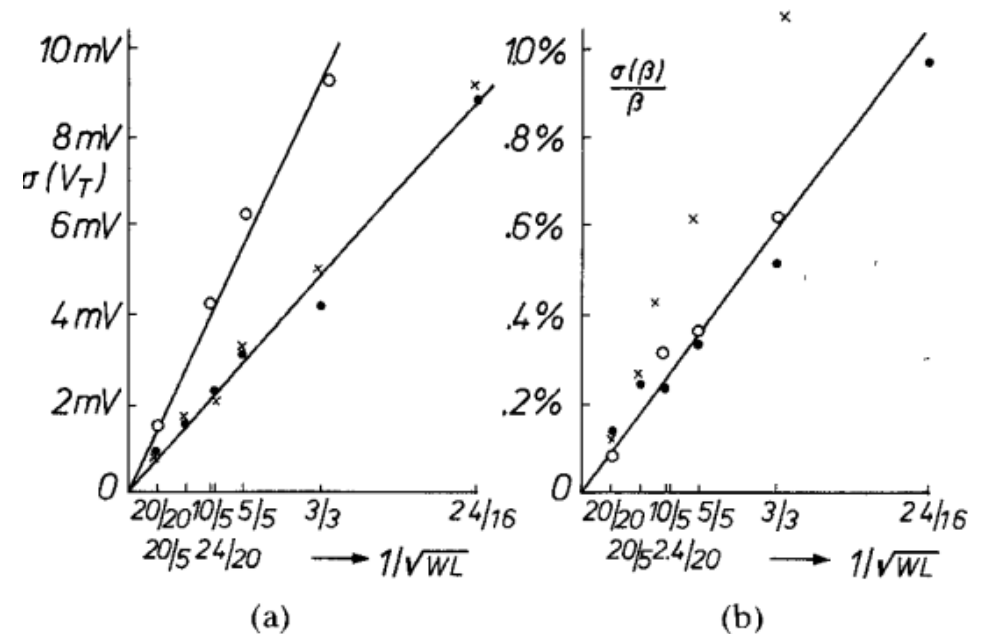
Mosfet

$$\sigma_{\frac{\Delta R}{R}} = \frac{C_R}{\sqrt{WL}}$$

Resistor

$C_{vt}$ ,  $C_{\beta}$  and  $C_R$  are constant parameters of the process. Their values are given in the Design Rule Manual, with names that depend on the foundry (there is no general convention).

$C_{vt}$  units are generally  $V \cdot \mu\text{m}$ , while  $C_{\beta}$  and  $C_R$  ones are  $\mu\text{m}$ .



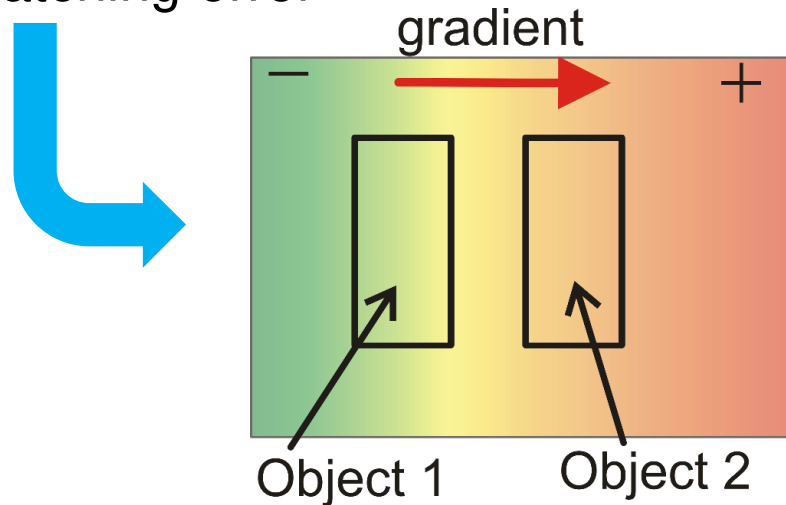
From: Pelgrom et al. IEEE J. of Solid State Circuits, 1989

## Matching Errors: Gradients

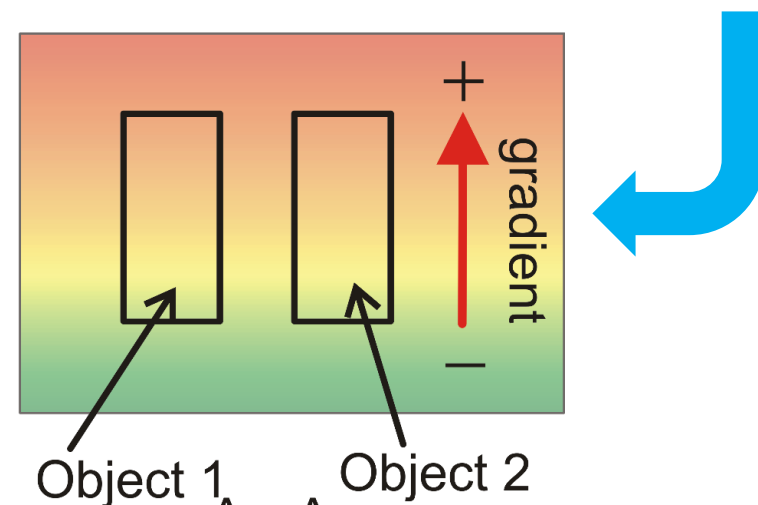
- Gradients indicate that important quantities that affect the device properties are not uniformly distributed on a macroscopic scale. This means that these quantities gradually varies across the chip area.
- Quantities of interest can be, for example:
  - ) Dopant density
  - ) Oxide thickness
- -) Geometrical process biases (e.g. etching undercut)
- -) Temperature (e.g. due to power devices present on the chip)
- -) Mechanical stress (mainly due to the packaging process)

## Effect of gradients on device matching

In this example radient causes matching error



For this case, gradient does not cause matching error



We consider a generic quantity "A"

$$A_1 < A_2$$

(a)

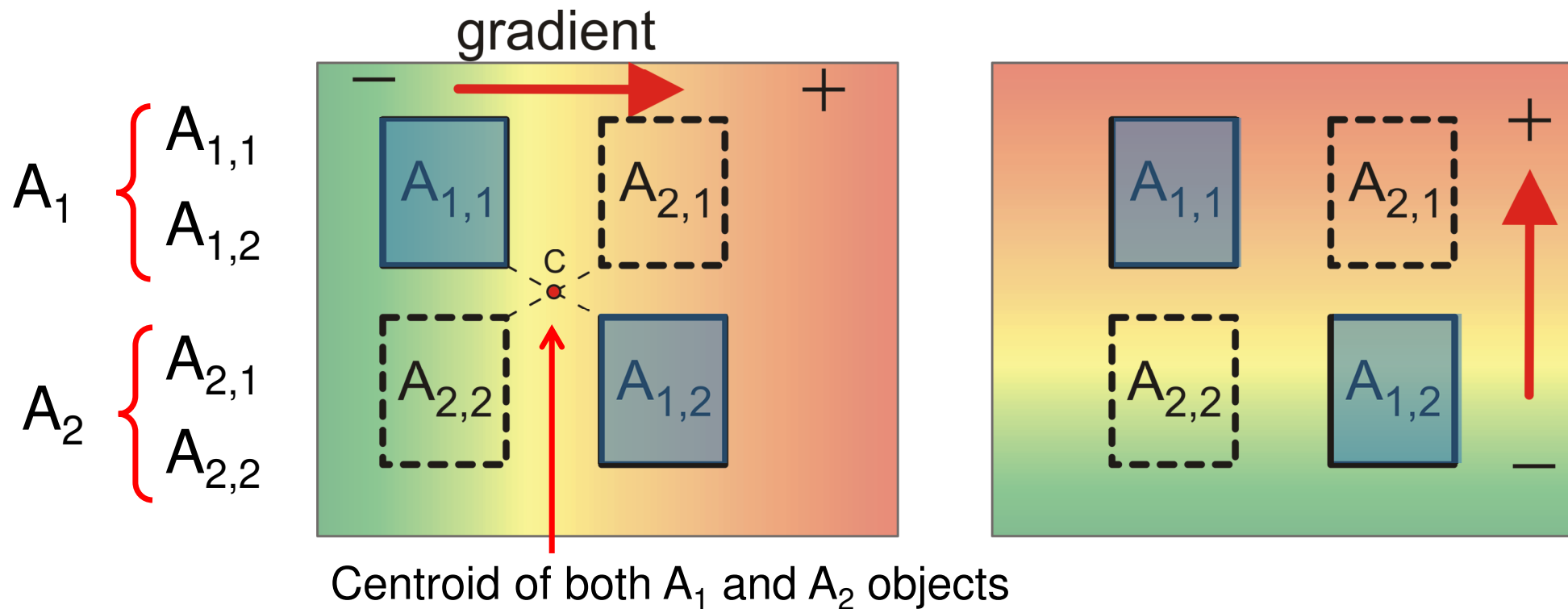
$$A_1 = A_2$$

(b)

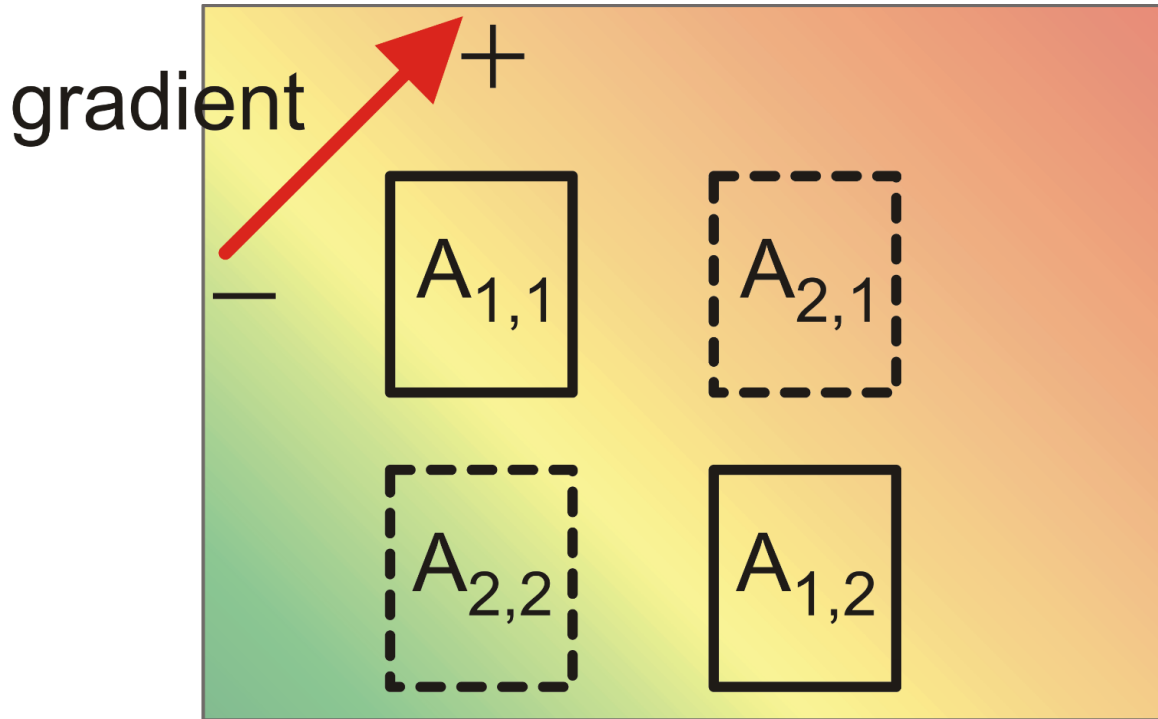
Unfortunately, in most cases, the direction of gradients is not predictable!

## Layout rules that prevent device mismatch caused by gradients

- Rule 1 (obvious): Take the distance between objects as close as possible.  
(This rule is less effective for large devices)
- Rule 2: Use common centroid configurations.



## Common centroid configuration: Oblique gradients



component	part	level
$A_1$	$A_{1,1}$	average
	$A_{1,2}$	average
$A_2$	$A_{2,1}$	high
	$A_{2,2}$	low

The common centroid configuration is effective also against oblique gradients..

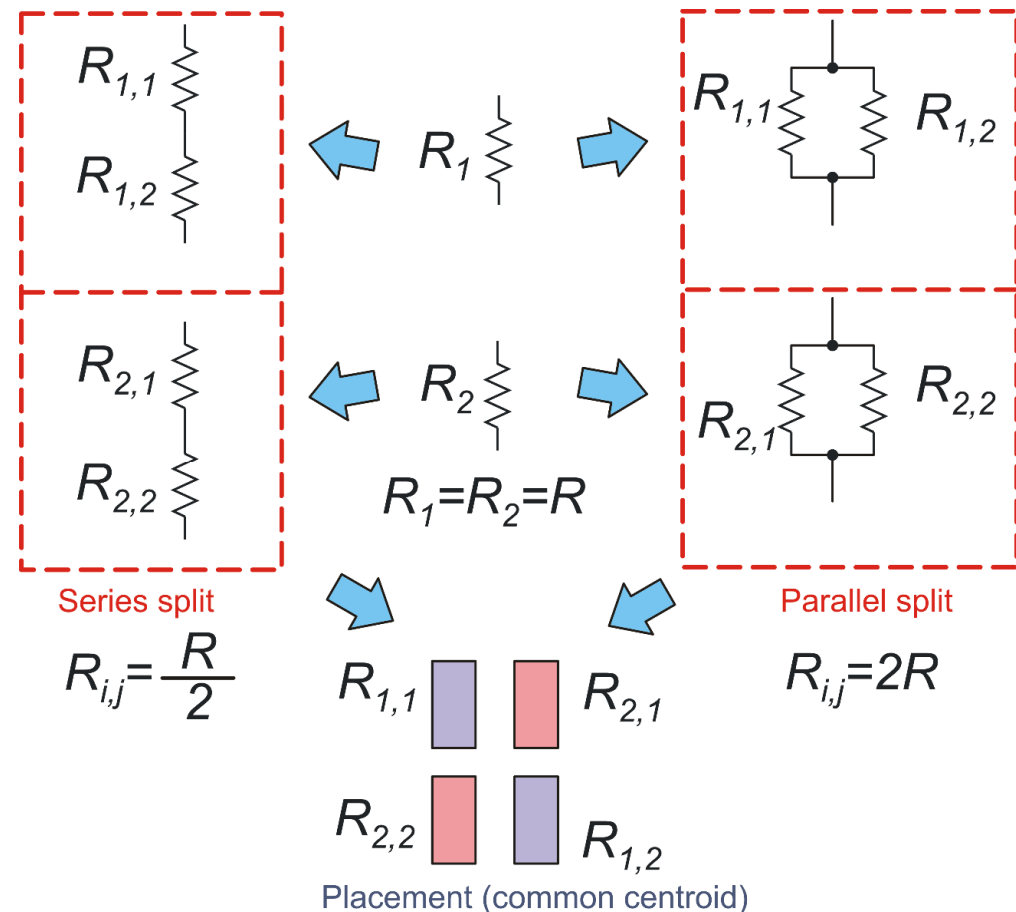


# Split and connect components in common centroid configurations

## Case 1::Resistors

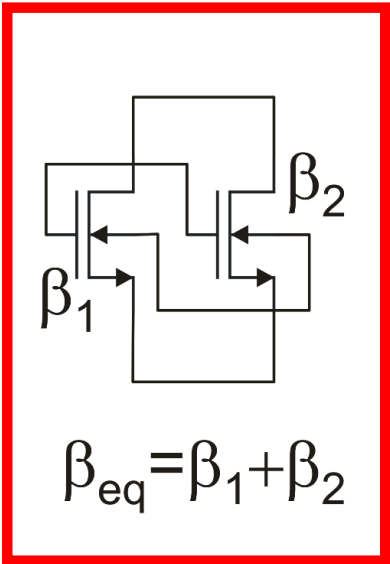
Series are preferred when resistors  $R_1$  and  $R_2$  are large

Parallels have to be preferred for small resistances

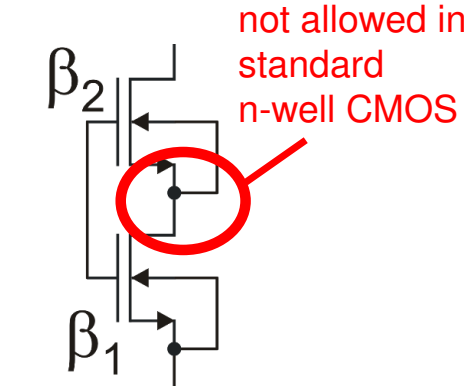


# Split and connect components in common centroid configurations

## Other devices - Properties of series and parallels

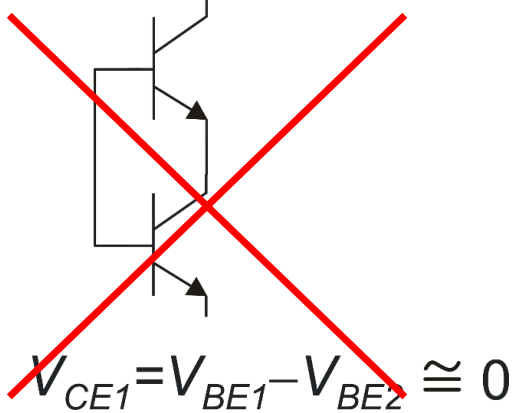
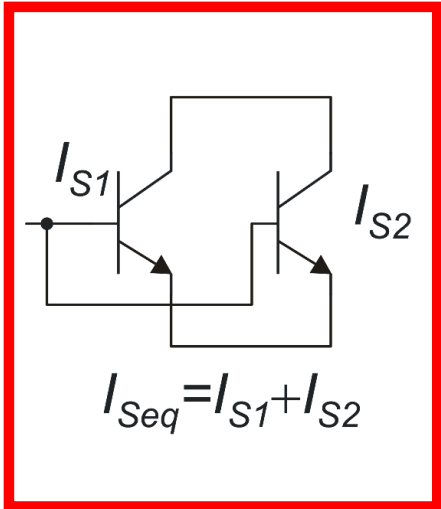


Accurate: Can be used in common centroid configurations



$$\frac{1}{\beta_{eq}} \cong \frac{1}{\beta_1} + \frac{1}{\beta_2}$$

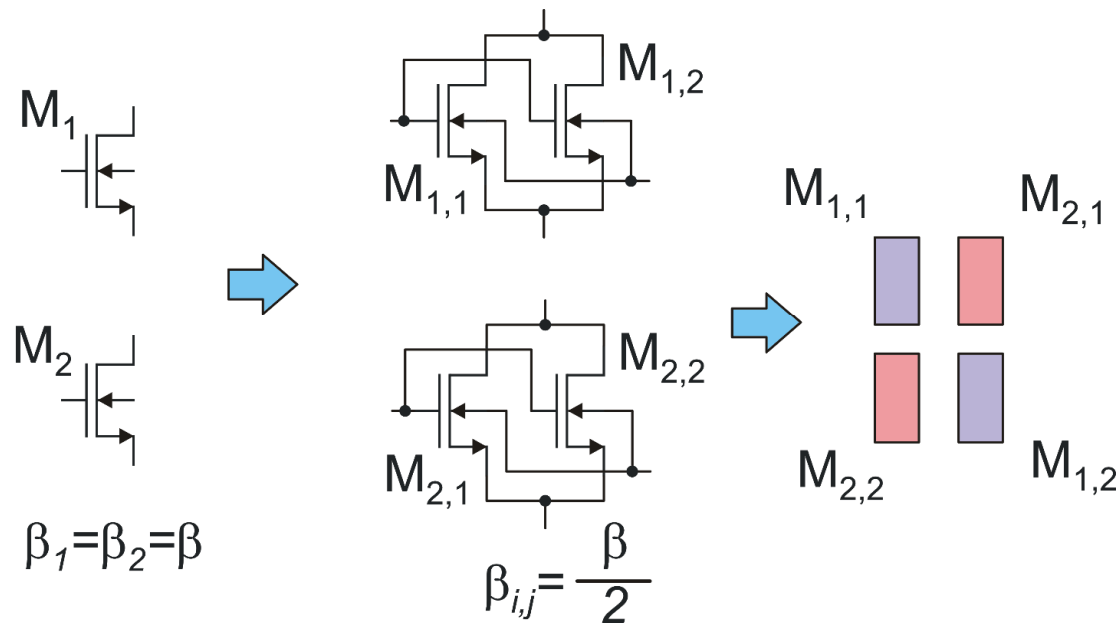
Not accurate



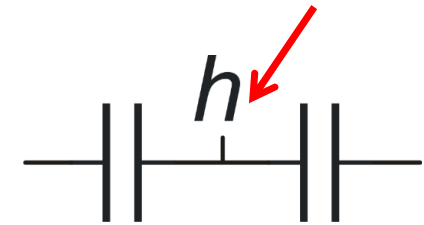
Don't use!

Split and connect components in common centroid configurations

## Case 2: MOSFETS



Floating node (no dc path)



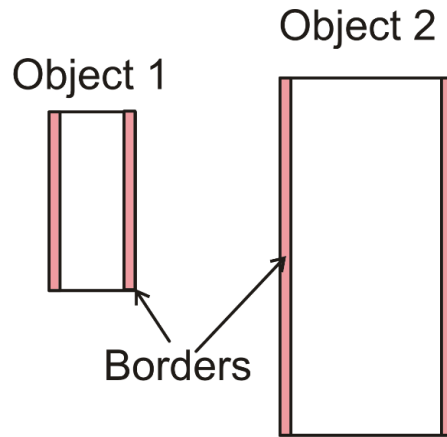
Series connections of capacitors have to be avoided as much as possible unless dc paths are provided for the floating node

**BJTs:** Same as Mosfets (parallels only)

**Capacitors:** Parallel connections are preferred (no floating nodes)

# Other Layout rules for improving device matching

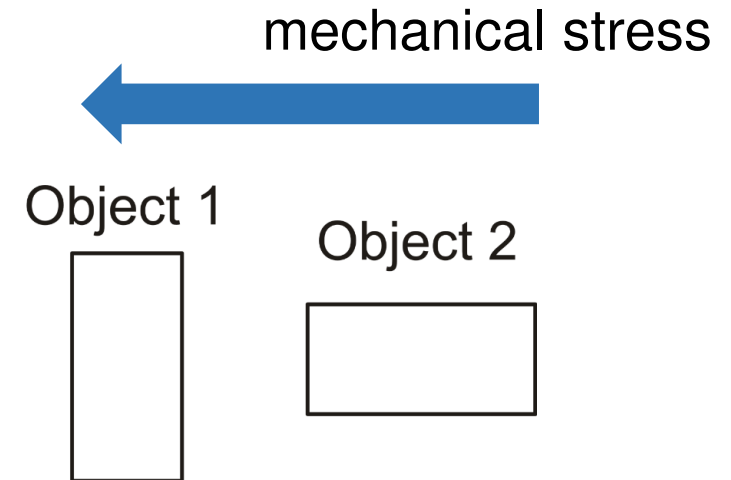
## Wrong solutions



$$\frac{W_1}{L_1} = \frac{W_2}{L_2}$$

~~~~  $R_1 = R_2$  resistors  
 $\beta_1 = \beta_2$  mosfets

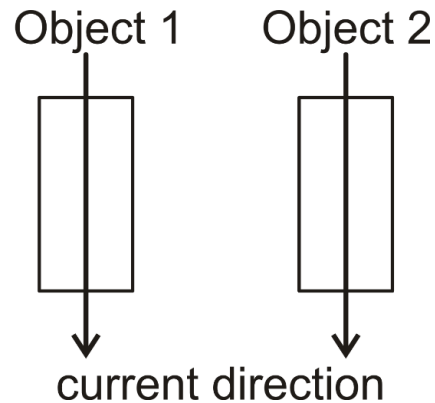
Different size: poor matching



Different orientation:  
poor matching

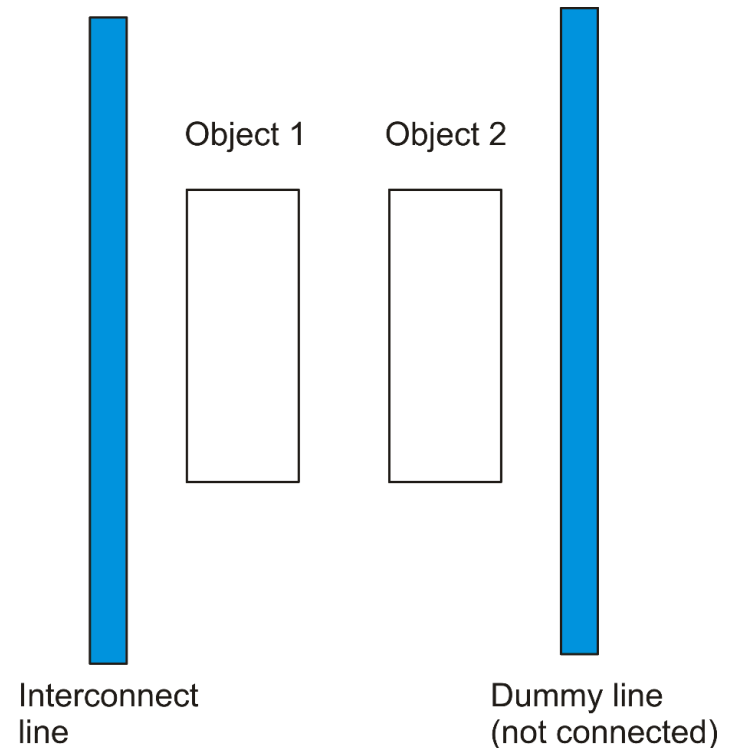
# Other Layout rules for improving device matching

Same direction  
(to match thermoelectric effects)



Temperature gradients  
develop extra voltage  
differences that depend on  
the current direction  
(up to several hundred  $\mu$ Vs)

Same surroundings

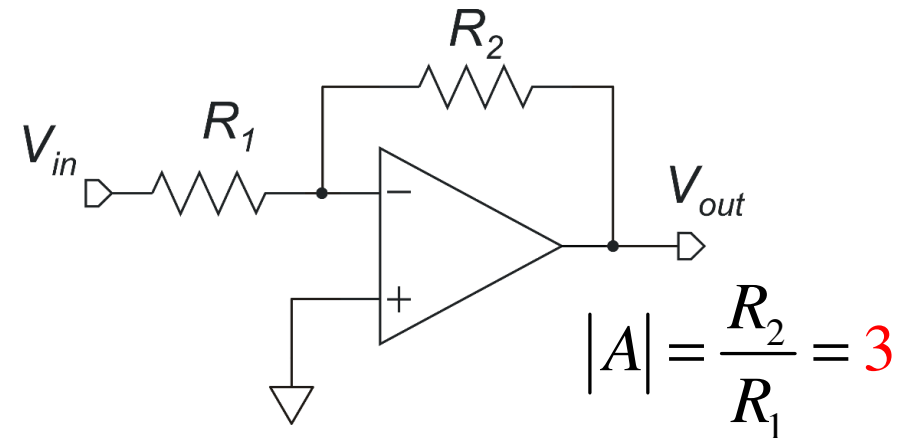


## Summary of rules for a good device matching

- Devices must be nominally identical (same dimensions, same orientation)
- Device areas should be as large as possible (Pelgrom model)
- Place devices as close as possible
- Use common centroid configurations
- Same current direction for the two devices
- The devices should "see" the same surroundings

## Rules to obtain accurate ratios

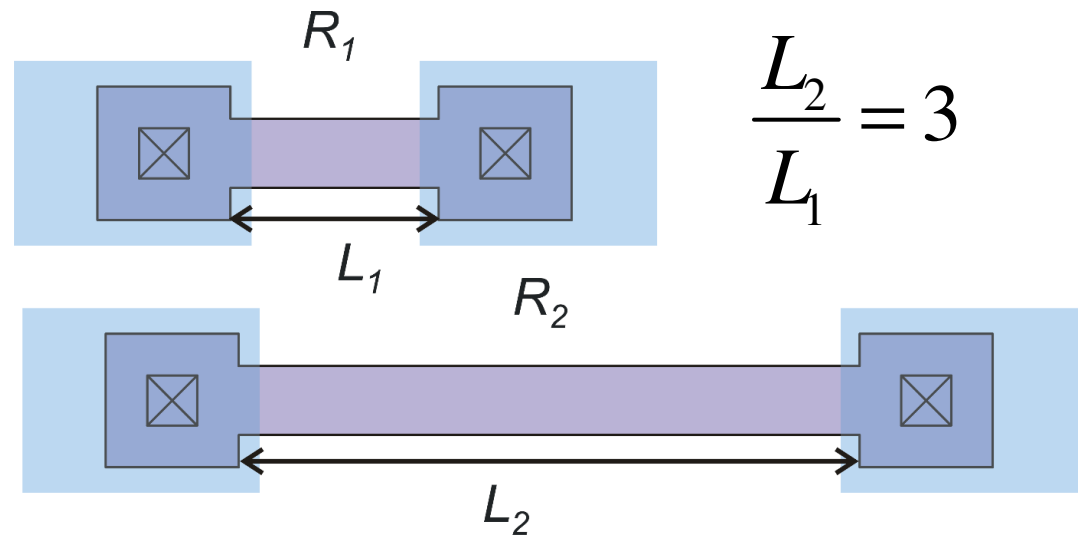
**Example:** accurate inverting amplifier with gain magnitude =3



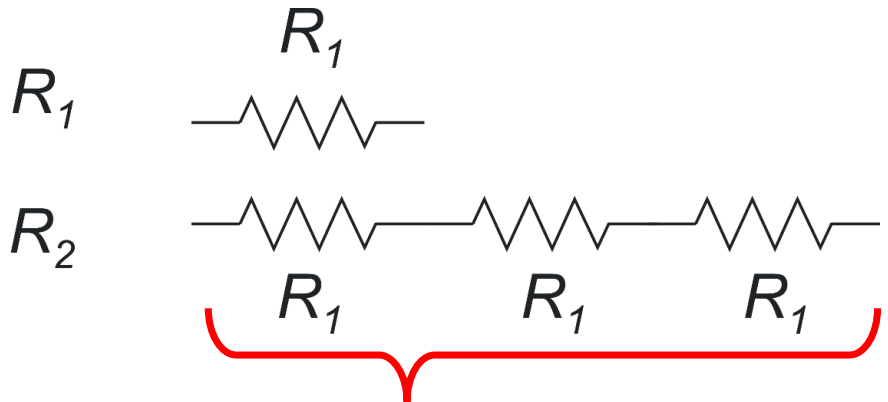
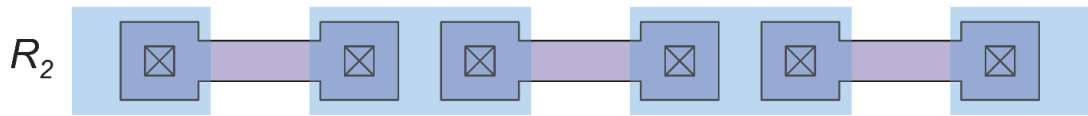
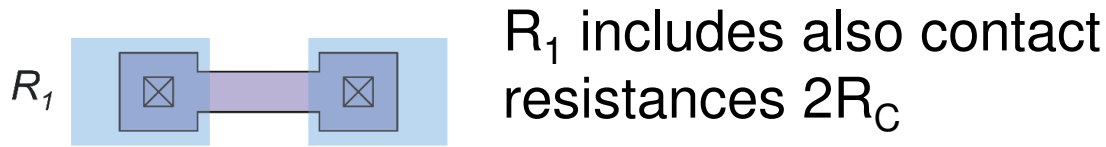
$$|A| = \frac{3R + 2R_C}{R + 2R_C} = 3 \left[ \frac{1 + (2/3)x}{1 + 2x} \right] < 3$$

$$x = \frac{R_C}{R} \quad (\text{e.g. with } x=0.1, \text{ er}=11\%)$$

**(systematic error)**

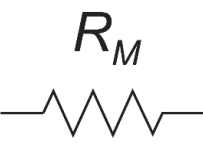
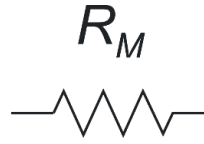


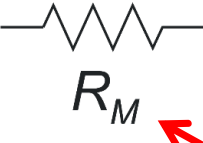
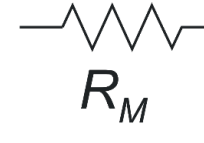
# Accurate ratios: modular components




$R_2$  is now exactly  $3 R_1$ , independently from contact resistances and other non idealities of  $R_1$

### Generalization to Fractional ratios

$R_1$   ---  M modules

$R_2$   ---  N modules

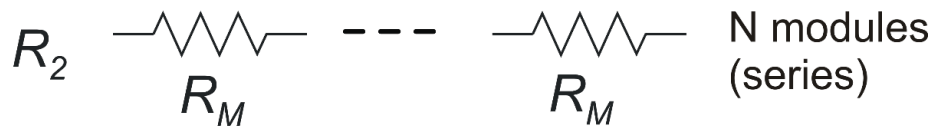
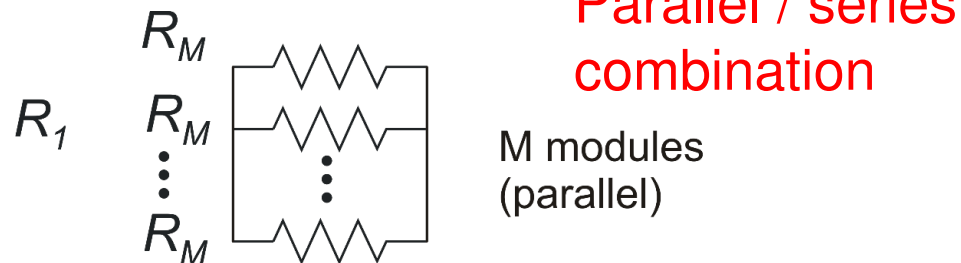
$R_M$   module

$$\frac{R_2}{R_1} = \frac{N}{M}$$

Both  $R_1$  and  $R_2$  are obtained by adding different numbers of a single module  $R_N$ .



## Accurate ratios: modular components

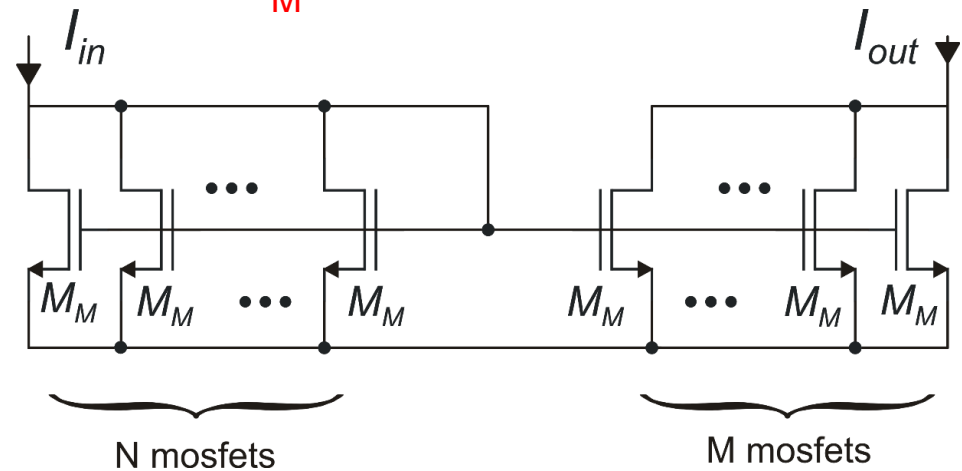


$$\frac{R_2}{R_1} = \frac{NR_M}{\frac{1}{M}R_M} = N \cdot M$$

Large ratios with less components

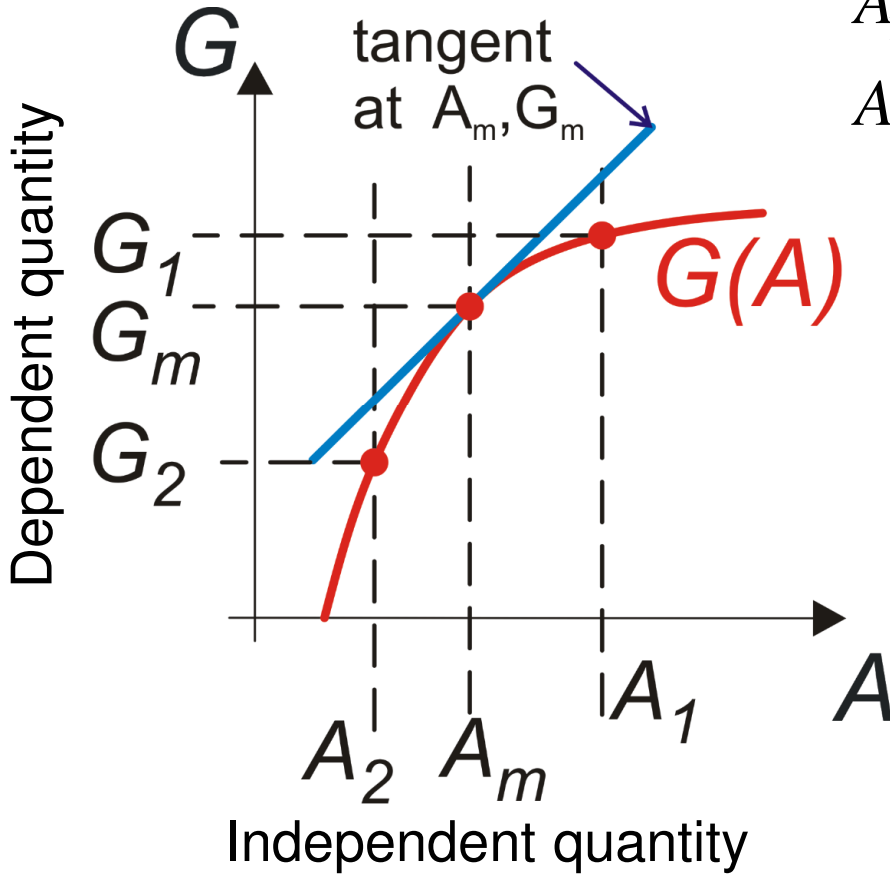
## Current mirror with accurate gain

$M_M = \text{Module}$



$$\frac{I_{out}}{I_{in}} = \frac{\beta_2}{\beta_1} = \frac{M \beta_M}{N \beta_M} = \frac{M}{N}$$

## Elements of error propagation theory



$$A_1 = A_m + \Delta A_1$$

$$\Delta A = A_1 - A_2 = \Delta A_1 - \Delta A_2$$

$$A_2 = A_m + \Delta A_2$$

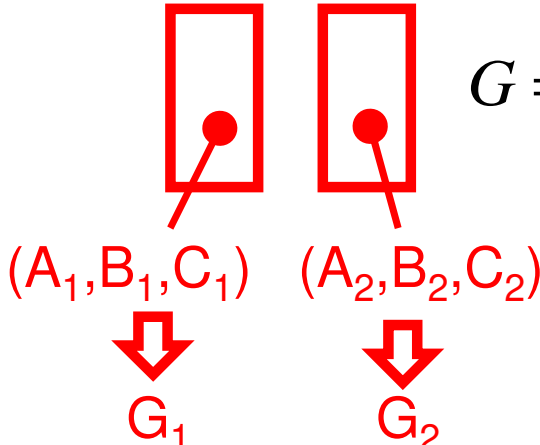
$A_m$  is an arbitrary value between  $A_1$  and  $A_2$

$$G_1 = G(A_m + \Delta A_1) \cong G(A_m) + \Delta A_1 \left. \frac{dG}{dA} \right|_{A=A_m}$$

$$G_2 = G(A_m + \Delta A_2) \cong G(A_m) + \Delta A_2 \left. \frac{dG}{dA} \right|_{A=A_m}$$

$$G_1 - G_2 \cong (\Delta A_1 - \Delta A_2) \left. \frac{dG}{dA} \right|_{A=A_m} = \Delta A \left. \frac{dG}{dA} \right|_{A=A_m}$$

For multiple independent variables - general case



$$G = f(A, B, C) \quad \Delta G = G_1 - G_2 = G(A_1, B_1, C_1) - G(A_2, B_2, C_2)$$

$$P_m = (A_m, B_m, C_m) \quad \begin{cases} G_1 = G(A_m + \Delta A_1, B_m + \Delta B_1, C_m + \Delta C_1) \\ G_2 = G(A_m + \Delta A_2, B_m + \Delta B_2, C_m + \Delta C_2) \end{cases}$$

$$\begin{cases} G_1 = G(A_m, B_m, C_m) + \Delta A_1 \left. \frac{\partial G}{\partial A} \right|_{P_m} + \Delta B_1 \left. \frac{\partial G}{\partial B} \right|_{P_m} + \Delta C_1 \left. \frac{\partial G}{\partial C} \right|_{P_m} \\ G_2 = G(A_m, B_m, C_m) + \Delta A_2 \left. \frac{\partial G}{\partial A} \right|_{P_m} + \Delta B_2 \left. \frac{\partial G}{\partial B} \right|_{P_m} + \Delta C_2 \left. \frac{\partial G}{\partial C} \right|_{P_m} \end{cases}$$

$$\Delta G = G_1 - G_2 = \Delta A \left. \frac{\partial G}{\partial A} \right|_{P_m} + \Delta B \left. \frac{\partial G}{\partial B} \right|_{P_m} + \Delta C \left. \frac{\partial G}{\partial C} \right|_{P_m}$$

## Error propagation: particular case 1

case 1:

posynomial expression

$$G(A, B, C) = A^\alpha B^\beta C^\gamma$$

←  $\alpha, \beta, \gamma$  : real exponents  
 $A, B, C$  real positive variables

$$\left. \frac{\partial G}{\partial A} \right|_{P_m} = \alpha A_m^{\alpha-1} B_m^\beta C_m^\gamma$$

Using:  $\Delta G = \Delta A \left. \frac{\partial G}{\partial A} \right|_{P_m} + \Delta B \left. \frac{\partial G}{\partial B} \right|_{P_m} + \Delta C \left. \frac{\partial G}{\partial C} \right|_{P_m}$

$$\left. \frac{\partial G}{\partial B} \right|_{P_m} = \beta A_m^\alpha B_m^{\beta-1} C_m^\gamma$$

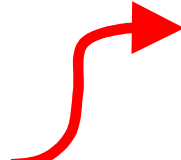
$$\Delta G = \alpha A_m^{\alpha-1} B_m^\beta C_m^\gamma \Delta A + \beta A_m^\alpha B_m^{\beta-1} C_m^\gamma \Delta B + \gamma A_m^\alpha B_m^\beta C_m^{\gamma-1} \Delta C$$

$$\left. \frac{\partial G}{\partial C} \right|_{P_m} = \gamma A_m^\alpha B_m^\beta C_m^{\gamma-1}$$

## Error propagation: particular case 1

case 1

$$G(A, B, C) = A^\alpha B^\beta C^\gamma$$

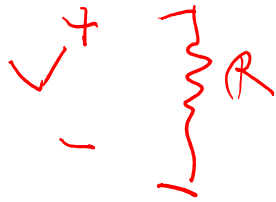
Relative variation (or relative error) 

$$\frac{\Delta G}{G_m} = \frac{\Delta G}{G(P_m)} = \frac{\Delta G}{A_m^\alpha B_m^\beta C_m^\gamma}$$

$$\frac{\Delta G}{G_m} = \frac{\alpha A_m^{\alpha-1} B_m^\beta C_m^\gamma \Delta A + \beta A_m^\alpha B_m^{\beta-1} C_m^\gamma \Delta B + \gamma A_m^\alpha B_m^\beta C_m^{\gamma-1} \Delta C}{A_m^\alpha B_m^\beta C_m^\gamma}$$

$$\frac{\Delta G}{G_m} = \alpha \frac{\Delta A}{A_m} + \beta \frac{\Delta B}{B_m} + \gamma \frac{\Delta C}{C_m}$$

Sum of the single relative errors, weighted by the respective exponents



$$P = \frac{V^2}{R}$$

$$V \rightarrow 10^{-1}\%$$

$$\frac{\Delta P}{P} = 2 \left( \frac{\Delta V}{V} \right) - \frac{\Delta R}{R}$$

0.1

## Error propagation: particular case 2

$$G(A, B, C) = \ln(A^\alpha B^\beta C^\gamma)$$

case 2: logarithm of a posinomial

$$Z = (A^\alpha B^\beta C^\gamma)$$
$$Z_m = (A_m^\alpha B_m^\beta C_m^\gamma)$$
$$\Delta G = \Delta Z \left. \frac{dG}{dZ} \right|_{Z=Z_m} = \Delta Z \left. \frac{d[\ln(Z)]}{dZ} \right|_{Z=Z_m} = \frac{\Delta Z}{Z_m}$$

$$\Delta G = \frac{\Delta Z}{Z} = \alpha \frac{\Delta A}{A_m} + \beta \frac{\Delta B}{B_m} + \gamma \frac{\Delta C}{C_m}$$

Here we have the absolute error of G, not the relative one.

## Application to matching errors

- Generally, when dealing with matching errors:  $A_m = \bar{A}$  (mean value)
- Matching errors has also the following basic property:

**Linearity:**  $G=A+B$   $\Delta G=\Delta A+\Delta B$

$G=kA$ , where  $k$  is a constant :  $\Delta G=k\Delta A$

- In the case of relative error, if  $G=kA$ :  $\frac{\Delta G}{G} = \frac{\Delta A}{A}$



- Matching errors: statistical independence
- Matching errors of different quantities (e.g., quantities A,B,C) can be often considered independent from each other since they are mostly affected by microscopic irregularities, that do not show significant correlations when pairs of quantities are considered.
- In addition matching errors of different device pairs can be also considered independent, or, at least, uncorrelated.

$$G = k_1 A + k_2 B + k_3 C \quad \Rightarrow \quad \sigma_{\Delta G} = \sqrt{k_1^2 \sigma_{\Delta A}^2 + k_2^2 \sigma_{\Delta B}^2 + k_3^2 \sigma_{\Delta C}^2}$$

$\Delta A$        $\Delta B$        $\Delta C$